ROHM

勝特力材料 886-3-5753170

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100mA / 50V Digital transistors (with built-in resistors)

DTC123JEB

•Applications

Inverter, Interface, Driver

Features

- Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see equivalent circuit).
- 2) The bias resistors consist of thin-film resistors with complete isolation to allow negative biasing of the input. They also have the advantage of almost completely eliminating parasitic effects.
- 3) Only the on/off conditions need to be set for operation, making the device design easy.

Structure

NPN silicon epitaxial planar transistor type (Resistor built-in)

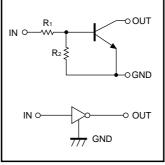
Packaging specifications

	Package	EMT3F
	Packaging type	Taping
	Code	TL
Part No.	Basic ordering unit (pieces)	3000
DTC123JEB		0

•Dimensions (Unit : mm) EMT3F 16 0.7 0.26 0.37 55 (3) 0.86 1.6 37, (1) (2) 0.13 0.5 0.5 1.0 (1) IN (2) GND (3) OUT Each lead has same dimensions

Abbreviated symbol : E42

Inner circuit



R1=2.2kΩ, R2=47kΩ

●Absolute maximum ratings (Ta=25°C)

Parameter	Symbol	Limits	Unit
Supply voltage	Vcc	50	V
Input voltage	Vin	-5 to +12	V
Collector current	Ic(max) *1	100	mA
Output current	lo	100	mA
Power dissipation	PD *2	150	mW
Junction temperature	Tj	150	°C
Range of storage temperature	Tstg	-55 to +150	°C

*1 Characteristics of built-in transistor

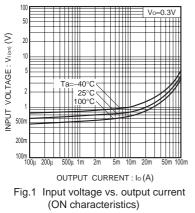
*2 Each terminal mounted on a recommended land

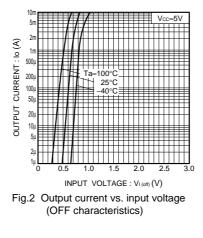
•Electrical characteristics (Ta=25°C)

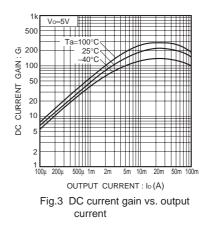
Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Innutveltere	VI(off)	-	-	500	mV	Vcc=5V, Io=100μA
Input voltage	VI(on)	1.1	-	-	V	Vo=0.3V, Io=5mA
Output voltage	VO(on)	-	100	300	mV	lo/l=5mA/0.25mA
Input current	h	-	-	3.6	mA	VI=5V
Output current	IO(off)	-	-	500	nA	Vcc=50V, Vi=0V
DC current gain	Gı	80	-	-	-	Vo=5V, Io=10mA
Transition frequency	f⊤ *	-	250	-	MHz	Vce=10V, Ie= -5mA, f=100MHz
Input resistance	R1	1.54	2.2	2.86	kΩ	_
Resistance ratio	R2/R1	17	21	26	_	_

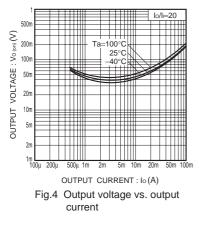
*Characteristics of built-in transistor

•Electrical characteristic curves









	Notes
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